

Data sheet acquired from Harris Semiconductor SCHS152D

### September 1997 - Revised June 2004

### Features

- Two Enable Inputs to Facilitate Demultiplexing and Cascading Functions
- Fanout (Over Temperature Range)
  - Standard Outputs ..... 10 LSTTL Loads
  - Bus Driver Outputs ..... 15 LSTTL Loads
- Wide Operating Temperature Range .... -55°C to 125°C
- · Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity: N<sub>IL</sub> = 30%, N<sub>IH</sub> = 30% of V<sub>CC</sub> at V<sub>CC</sub> = 5V
- HCT Types
  - 4.5V to 5.5V Operation
  - Direct LSTTL Input Logic Compatibility, V<sub>IL</sub>= 0.8V (Max), V<sub>IH</sub> = 2V (Min)
  - CMOS Input Compatibility, I<sub>I</sub>  $\leq$  1µA at V<sub>OL</sub>, V<sub>OH</sub>

### Description

The 'HC154 and 'HCT154 are 4- to 16-line decoders/demultiplexers with two enable inputs, E1 and E2.

# 4- to 16-Line Decoder/Demultiplexer

**High-Speed CMOS Logic** 

CD54HC154, CD74HC154, CD54HCT154, CD74HCT154

A High on either enable input forces the output into the High state. The demultiplexing function is performed by using the four input lines, A0 to A3, to select the output lines  $\overline{Y0}$  to  $\overline{Y15}$ , and using one enable as the data input while holding the other enable low.

### **Ordering Information**

PART NUMBER	TEMP. RANGE ( <sup>o</sup> C)	PACKAGE
CD54HC154F3A	-55 to 125	24 Ld CERDIP
CD54HCT154F3A	-55 to 125	24 Ld CERDIP
CD74HC154E	-55 to 125	24 Ld PDIP
CD74HC154EN	-55 to 125	24 Ld PDIP
CD74HC154M	-55 to 125	24 Ld SOIC
CD74HC154M96	-55 to 125	24 Ld SOIC
CD74HCT154E	-55 to 125	24 Ld PDIP
CD74HCT154EN	-55 to 125	24 Ld PDIP
CD74HCT154M	-55 to 125	24 Ld SOIC
CD74HCT154M96	-55 to 125	24 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel.

### Pinout

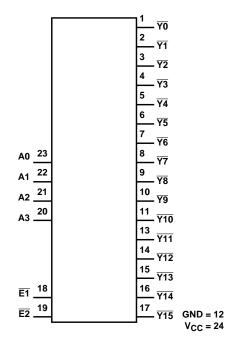
CD74H	(OLICE) IC154, CD74H0 (PDIP, SOIC) TOP VIEW	ст	154
Y0 1 Y1 2 3 Y2 3 4 Y3 4 5 Y5 6 7 Y7 8 Y6 7 Y7 8		24 23 22 21 20 19 18 17 49	V <sub>CC</sub> A0 A1 A2 A3 E2 E1 Y15 Y14
Y8     9       Y9     10       Y10     11       GND     12		16 15 14 13	Y13 Y12 Y11

CD54HC154, CD54HCT154 (CERDIP)

CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

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# Functional Diagram



### TRUTH TABLE

		INP	UTS										OUT	PUTS							
E1	E2	A3	A2	A1	A0	¥0	<u>Y1</u>	<u>Y2</u>	<u>¥3</u>	<u>¥4</u>	<u>Y5</u>	¥6	<b>Y7</b>	<u>¥8</u>	<u>Y9</u>	<u>Y10</u>	<u>Y11</u>	<u>Y12</u>	<b>Y13</b>	<u>Y14</u>	Y15
L	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
L	L	L	L	L	Н	Н	L	Н	н	Н	Н	Н	н	н	Н	Н	Н	Н	Н	Н	н
L	L	L	L	н	L	н	Н	L	н	Н	Н	н	н	н	н	Н	Н	н	Н	н	н
L	L	L	L	н	н	н	Н	Н	L	Н	Н	н	н	н	н	Н	Н	н	Н	н	н
L	L	L	н	L	L	н	Н	Н	н	L	Н	н	н	н	н	Н	Н	н	Н	н	н
L	L	L	н	L	н	Н	Н	Н	н	Н	L	н	н	н	н	Н	Н	н	Н	н	н
L	L	L	н	н	L	Н	Н	Н	н	Н	Н	L	н	н	н	Н	Н	н	Н	н	н
L	L	L	Н	Н	Н	Н	Н	Н	н	Н	Н	Н	L	н	Н	Н	Н	Н	Н	Н	н
L	L	н	L	L	L	H	Η	Η	Н	Η	Η	н	н	L	H	Η	Н	н	Η	Н	н
L	L	н	L	L	Н	H	Η	Η	Н	Η	Η	Η	н	н	L	Η	Н	н	Η	Н	н
L	L	н	L	H	L	H	Η	Η	Н	Η	Η	Η	н	н	H	L	Н	н	Η	Н	н
L	L	н	L	H	Н	H	Η	Η	Н	Η	Η	Η	н	н	H	Η	L	н	Η	Н	н
L	L	н	Н	L	L	H	Η	Η	Н	Η	Η	Η	н	н	H	Η	Н	L	Η	Н	н
L	L	н	Н	L	Н	H	Η	Η	Н	Η	Η	Η	н	н	H	Η	Н	н	L	Н	н
L	L	н	Н	H	L	H	Η	Η	Н	Η	Η	Η	н	н	H	Η	Н	н	Η	L	н
L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	н	н	Н	Н	Н	Н	Н	Н	L
L	Н	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	н	н	Н	Н	Н	Н	Н	Н	н
н	L	Х	Х	Х	Х	Н	Η	Н	Н	Н	Н	Н	Н	н	Н	Η	Н	Н	Η	Н	н
н	Н	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	н

H = High Voltage Level, L = Low Voltage Level, X = Don't Care

### **Absolute Maximum Ratings**

DC Supply Voltage, V <sub>CC</sub>
DC Input Diode Current, I <sub>IK</sub>
For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$ ±20mA
DC Output Diode Current, I <sub>OK</sub>
For $V_0 < -0.5V$ or $V_0 > V_{CC} + 0.5V$
DC Output Source or Sink Current per Output Pin, IO
For $V_0 > -0.5V$ or $V_0 < V_{CC} + 0.5V$
DC V <sub>CC</sub> or Ground Current, I <sub>CC or</sub> I <sub>GND</sub> ±50mA

### **Operating Conditions**

Temperature Range (T <sub>A</sub> )55°C to 125°C
Supply Voltage Range, V <sub>CC</sub>
HC Types
HCT Types
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub> 0V to V <sub>CC</sub>
Input Rise and Fall Time
2V
4.5V
6V

### **Thermal Information**

Thermal Resistance (Typical)	θ <sub>JA</sub> ( <sup>o</sup> C/W)
E (PDIP) Package (.600) (Note 1)	67
EN (PDIP) Package (.300) (Note 1)	67
M (SOIC) Package (Note 2)	46
Maximum Junction Temperature	150 <sup>0</sup> C
Maximum Storage Temperature Range6	65 <sup>0</sup> C to 150 <sup>0</sup> C
Maximum Lead Temperature (Soldering 10s) (SOIC - Lead Tips Only)	300 <sup>0</sup> C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

### NOTES:

1. The package thermal impedance is calculated in accordance with JESD 51-3.

2. The package thermal impedance is calculated in accordance with JESD 51-7.

### **DC Electrical Specifications**

		TE: CONDI		V <sub>CC</sub>		25 <sup>0</sup> C		-40°C TO 85°C		-55°C TO 125°C		4
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input	VIH	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	VIL	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V <sub>OH</sub>	$V_{\text{IH}} \text{ or } V_{\text{IL}}$	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
CINCO LOUGO			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output			-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V <sub>OL</sub>	$V_{IH}$ or $V_{IL}$	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
CINCO LOUGO			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output	1		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	6	-	-	8	-	80	-	160	μA

## CD54HC154, CD74HC154, CD54HCT154, CD74HCT154

### DC Electrical Specifications (Continued)

		TES CONDI		V <sub>CC</sub>		25 <sup>0</sup> C		-40°C T	O 85°C	-55°C T	O 125ºC	
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES												
High Level Input Voltage	VIH	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	II	V <sub>CC</sub> and GND	0	5.5	-		±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	5.5	-	-	8	-	80	-	160	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	∆I <sub>CC</sub> (Note 3)	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μA

NOTE:

3. For dual-supply systems theoretical worst case (V<sub>I</sub> = 2.4V, V<sub>CC</sub> = 5.5V) specification is 1.8mA.

### **HCT Input Loading Table**

INPUT	UNIT LOADS
A0 - A3	1.4
Ē1, Ē2	1.3

NOTE: Unit Load is  $\Delta I_{CC}$  limit specified in DC Electrical Table, e.g., 360µA max at 25°C.

### Switching Specifications Input $t_r$ , $t_f = 6ns$

		TEST		25°C			-40 <sup>0</sup> 85	сто °C	-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	$V_{CC}(V)$	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES									_	_	
Propagation Delay (Figure 1)	t <sub>PLH</sub> , t <sub>PHL</sub>	$C_L = 50 pF$	2	-	-	175	-	220	-	265	ns
Address to Output			4.5	-	-	35	-	44	-	53	ns
		C <sub>L</sub> =15pF	5	-	14	-	-	-	-	-	ns
		$C_L = 50 pF$	6	-	-	30	-	37	-	45	ns

# CD54HC154, CD74HC154, CD54HCT154, CD74HCT154

		TEST			25 <sup>0</sup> C			с то °С	-55 <sup>0</sup> C T	O 125 <sup>0</sup> C	
PARAMETER	SYMBOL	CONDITIONS	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
E1 to Output	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	-	175	-	220	-	265	ns
			4.5	-	-	35	-	44	-	53	ns
		C <sub>L</sub> =15pF	5	-	14	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	30	-	37	-	45	ns
E2 to Output	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	-	175	-	220	-	265	ns
			4.5	-	-	35	-	44	-	53	ns
		C <sub>L</sub> =15pF	5	-	14	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	30	-	37	-	45	ns
Output Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	2	-	-	75	-	95	-	110	ns
(Figure 1)			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	C <sub>IN</sub>	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 4, 5)	C <sub>PD</sub>	-	5	-	88	-	-	-	-	-	pF
HCT TYPES											
Propagation Delay (Figure 2) Address to Output	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	35	-	44	-	53	ns
		C <sub>L</sub> =15pF	5	-	14	-	-		-	-	ns
E1 to Output	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	34	-	43	-	51	ns
		C <sub>L</sub> =15pF	5	-	14	-	-	-	-	-	ns
E2 to Output	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-		34	-	43	-	51	ns
		C <sub>L</sub> =15pF	5	-	14	-	-	-	-	-	ns
Output Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	15	-	19	-	22	ns
Input Capacitance	C <sub>IN</sub>	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 4, 5)	C <sub>PD</sub>	-	5		84	-	-	-	-	-	pF

NOTES:

4.  $C_{\mbox{PD}}$  is used to determine the dynamic power consumption, per gate.

5.  $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$  where  $f_i$  = input frequency,  $C_L$  = output load capacitance,  $V_{CC}$  = supply voltage.

### Test Circuits and Waveforms

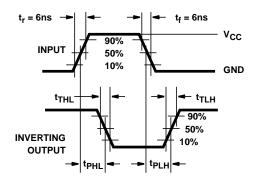


FIGURE 1. HC AND HCU TRANSITION TIMES AND PROPAGA-TION DELAY TIMES, COMBINATION LOGIC

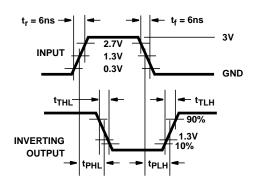


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC



18-Oct-2013

### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
5962-8670101JA	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-8670101JA CD54HCT154F3A	Samples
5962-8682201JA	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-8682201JA CD54HC154F3A	Samples
CD54HC154F3A	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-8682201JA CD54HC154F3A	Samples
CD54HCT154F3A	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-8670101JA CD54HCT154F3A	Samples
CD74HC154E	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC154E	Samples
CD74HC154EE4	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC154E	Samples
CD74HC154EN	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC154EN	Samples
CD74HC154ENE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC154EN	Samples
CD74HC154M	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC154M	Samples
CD74HC154M96	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU   CU SN	Level-1-260C-UNLIM	-55 to 125	HC154M	Samples
CD74HC154M96E4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC154M	Samples
CD74HC154M96G4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC154M	Samples
CD74HC154ME4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC154M	Samples
CD74HC154MG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC154M	Samples
CD74HCT154E	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT154E	Samples
CD74HCT154EE4	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT154E	Samples
CD74HCT154EN	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT154EN	Samples



18-Oct-2013

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CD74HCT154ENE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT154EN	Samples
CD74HCT154M	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT154M	Samples
CD74HCT154M96	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT154M	Samples
CD74HCT154M96E4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT154M	Samples
CD74HCT154M96G4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT154M	Samples
CD74HCT154ME4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT154M	Samples
CD74HCT154MG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT154M	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



# PACKAGE OPTION ADDENDUM

18-Oct-2013

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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### OTHER QUALIFIED VERSIONS OF CD54HC154, CD54HCT154, CD74HC154, CD74HC154;

- Catalog: CD74HC154, CD74HCT154
- Military: CD54HC154, CD54HCT154

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC154M96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD74HC154M96G4	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD74HCT154M96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

21-Jun-2013



\*All dimensions are nominal

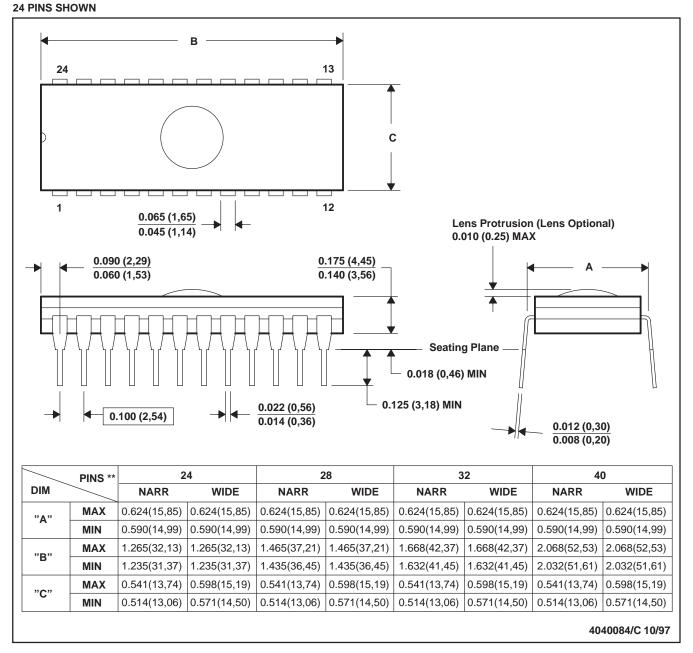
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC154M96	SOIC	DW	24	2000	366.0	364.0	50.0
CD74HC154M96G4	SOIC	DW	24	2000	367.0	367.0	45.0
CD74HCT154M96	SOIC	DW	24	2000	367.0	367.0	45.0

# **MECHANICAL DATA**

MCDI004A - JANUARY 1995 - REVISED NOVEMBER 1997

### **CERAMIC DUAL-IN-LINE PACKAGE**

J (R-GDIP-T\*\*)



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Window (lens) added to this group of packages (24-, 28-, 32-, 40-pin).
- D. This package can be hermetically sealed with a ceramic lid using glass frit.
- E. Index point is provided on cap for terminal identification.



NT (R-PDIP-T\*\*) 24 pins shown

PLASTIC DUAL-IN-LINE PACKAGE



All integrations are in minimeters. Dimensioning and toil
B. This drawing is subject to change without notice.

The 28 pin end lead shoulder width is a vendor option, either half or full width.

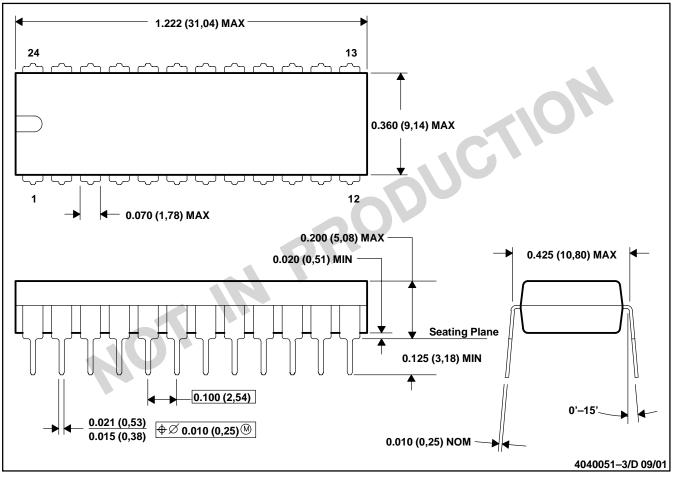


# **MECHANICAL DATA**

MPDI006B - SEPTEMBER 2001 - REVISED APRIL 2002

### N (R-PDIP-T24)

### PLASTIC DUAL-IN-LINE



- NOTES: A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Falls within JEDEC MS-010



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AD.



# LAND PATTERN DATA



NOTES:

A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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